



# 60 V PNP MEDIUM POWER TRANSISTOR



CZT751 SOT-223 Plastic Pakage

### **COMPLEMENTRY TYPE – CZT651**

## **Maximum Ratings** @ $T_A = 25^{\circ}C$ unless otherwise specified

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V <sub>cbo</sub>	-80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Continuous Collector Current	I <sub>c</sub>	-3	А
Peak Pulse Current	I <sub>CM</sub>	-6	А

#### **Thermal Characteristics**

PARAMETER	SYMBOL	VALUE	UNIT	
Power Dissipation at T <sub>A</sub> =25°C	P <sub>D</sub>	2	W	
Operating and Storage Temperature Range	Τ <sub>J</sub> , Τ <sub>stg</sub>	-55 to 150	°C	





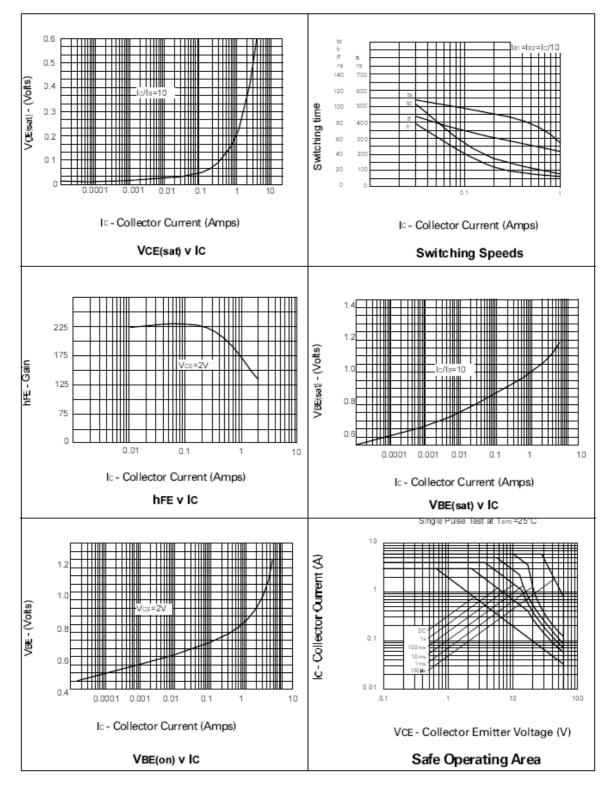
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	V (BR)CBO	Ι <sub>c</sub> = -100μΑ	-80			V
Collector-Emitter Breakdown Voltage *	V (BR)CEO	I <sub>c</sub> = -10mA	-60			v
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	Ι <sub>Ε</sub> = 100μΑ	-5			v
Collector Cut-off Current	I <sub>сво</sub>	V <sub>CB</sub> = -60V			-0.1	μA
		V <sub>CB</sub> = -60V, T <sub>amb</sub> = 100°C			-10	μA
Emitter Cut-off Current	ا <sub>EBO</sub>	V <sub>EB</sub> = -4V			-0.1	μA
Collector-Emitter Saturation Voltage *	V <sub>CE(SAT)</sub>	I <sub>c</sub> = -1A, I <sub>B</sub> = -100mA		-0.15	-0.3	V
		I <sub>c</sub> = -3A, I <sub>B</sub> = -300mA		-0.45	-0.6	V
Base-Emitter Saturation Voltage *	V <sub>CE(SAT)</sub>	I <sub>c</sub> = -1A, I <sub>B</sub> = -100mA		-0.9	-1.25	V
Base-Emitter Turn-On Voltage *	V <sub>BE(ON)</sub>	I <sub>c</sub> = -1A, V <sub>ce</sub> = -2V		-0.8	-1.25	V
DC Current Gain *		I <sub>c</sub> = -50mA, V <sub>ce</sub> = -2V	70	200		
	h <sub>FE</sub>	I <sub>c</sub> = -500mA, V <sub>ce</sub> = -2V	100	200	300	
		$I_{c} = -1A, V_{ce} = -2V$	80	170		
		I <sub>c</sub> = -2A, V <sub>ce</sub> = -2V	40	150		
Current Gain-Bandwidth Product *	f <sub>T</sub>	V <sub>ce</sub> = -5V, I <sub>c</sub> = -100mA, f = 100MHz	100	140		MHz
Turn-On Time	t <sub>on</sub>	V $_{\rm cc}$ = -10V, I $_{\rm c}$ = -500mA		40		ns
Turn-Off Time	t <sub>off</sub>	I <sub>B1</sub> = I <sub>B2</sub> = -50mA		450		ns
Output Capacitance *	C <sub>obo</sub>	V <sub>св</sub> = -10V. f = 1MHz			30	рF

## **Electrical Characteristics** @ $T_A$ = 25°C unless otherwise specified

\* Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ 







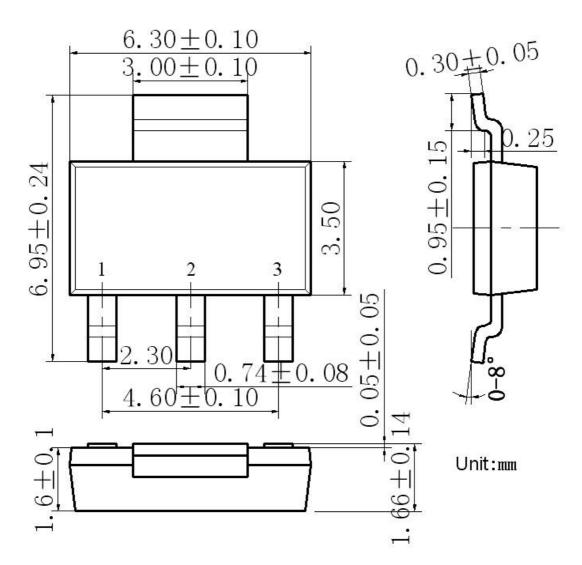
#### **CHARACTERISTICS CURVES**

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## PACKAGE OUTLINE AND DIMENSION millimeters(mm) SOT-223



1. BASE

2. COLLECTOR

3. EMITTER





**Customer Notes:** 

#### **Component Disposal Instructions**

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.

2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

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Data Sheet